HEF4060B

14-stage ripple-carry binary counter/divider and oscillator Rev. 05 — 27 November 2009 Product data s

Product data sheet

General description 1.

The HEF4060B is a 14-stage ripple-carry binary counter/divider and oscillator with three oscillator terminals (RS, REXT and CEXT), ten buffered outputs (Q3 to Q9 and Q11 to Q13) and an overriding asynchronous master reset input (MR).

The oscillator configuration allows design of either RC or crystal oscillator circuits. The oscillator may be replaced by an external clock signal at input RS. The clock input's Schmitt-trigger action makes it highly tolerant to slower clock rise and fall times. The counter advances on the negative-going transition of RS. A HIGH level on MR resets the counter (Q3 to Q9 and Q11 to Q13 = LOW), independent of other input conditions.

It operates over a recommended V_{DD} power supply range of 3 V to 15 V referenced to V_{SS} (usually ground). Unused inputs must be connected to V_{DD}, V_{SS}, or another input. It is also suitable for use over the full industrial (-40 °C to +85 °C) temperature range.

2. **Features**

- Tolerant of slow clock rise and fall times
- Fully static operation
- 5 V, 10 V, and 15 V parametric ratings
- Standardized symmetrical output characteristics
- Inputs and outputs are protected against electrostatic effects
- Operates across the full industrial temperature range -40 °C to +85 °C
- Complies with JEDEC standard JESD 13-B

Applications

Industrial

Ordering information

Table 1. **Ordering information**

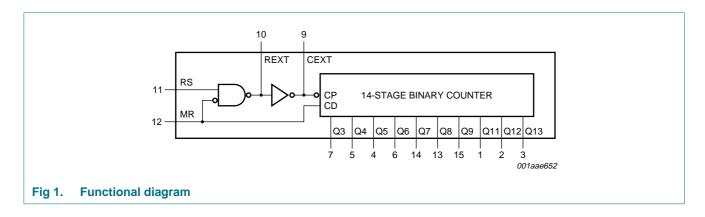
All types operate from -40 °C to +85 °C.

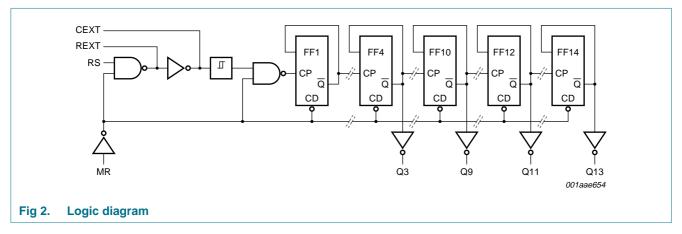
Type number	Package							
	Name	Description	Version					
HEF4060BP	DIP16	plastic dual in-line package; 16 leads (300 mil)	SOT38-4					
HEF4060BT	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1					



14-stage ripple-carry binary counter/divider and oscillator

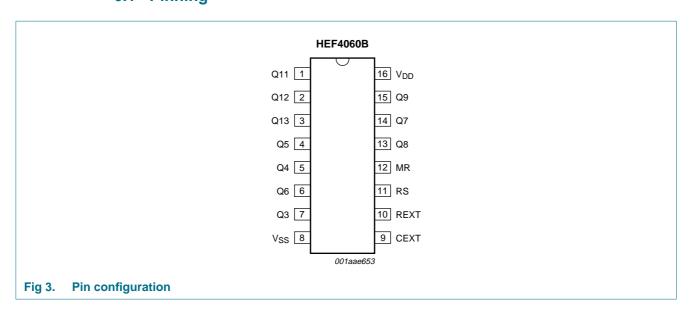
5. Functional diagram





6. Pinning information

6.1 Pinning



14-stage ripple-carry binary counter/divider and oscillator

6.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
Q11 to Q13	1, 2, 3	counter output
Q3 to Q9	7, 5, 4, 6, 14, 13, 15	counter output
V _{SS}	8	ground supply voltage
CEXT	9	external capacitor connection
REXT	10	oscillator pin
RS	11	clock input/oscillator pin
MR	12	master reset
V_{DD}	16	supply voltage

7. Functional description

Table 3. Function table[1]

Input	Output	
RS	MR	Q3 to Q9 and Q11 to Q13
\uparrow	L	no change
\downarrow	L	count
X	Н	L

8. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DD}	supply voltage		-0.5	+18	V
I _{IK}	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{DD} + 0.5 \text{ V}$	-	±10	mA
V_{I}	input voltage		-0.5	$V_{DD} + 0.5$	V
I_{OK}	output clamping current	$V_O < -0.5 \text{ V or } V_O > V_{DD} + 0.5 \text{ V}$	-	±10	mA
I _{I/O}	input/output current		-	±10	mA
I_{DD}	supply current		-	50	mA
T_{stg}	storage temperature		-65	+150	°C
T _{amb}	ambient temperature		-40	+85	°C
P _{tot}	total power dissipation	T_{amb} –40 °C to +85 °C			
		DIP16 package	[1] _	750	mW
		SO16 package	[2] _	500	mW
Р	power dissipation	per output	-	100	mW

^[1] For DIP16 package: P_{tot} derates linearly with 12 mW/K above 70 °C.

^[2] For SO16 package: P_{tot} derates linearly with 8 mW/K above 70 °C.

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9. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{DD}	supply voltage		3	-	15	V
V_{I}	input voltage		0	-	V_{DD}	V
T _{amb}	ambient temperature	in free air	-40	-	+85	°C
Δt/ΔV	input transition rise and fall	input MR				
	rate	$V_{DD} = 5 V$	-	-	3.75	μs/V
		$V_{DD} = 10 \text{ V}$	-	-	0.5	μs/V
		$V_{DD} = 15 \text{ V}$	-	-	0.08	μs/V

10. Static characteristics

Table 6. Static characteristics

 $V_{SS} = 0 \ V$; $V_I = V_{SS}$ or V_{DD} unless otherwise specified.

Symbol	Parameter	Conditions	V _{DD}	T _{amb} = -40 °C		T _{amb} = 25 °C		T _{amb} = 85 °C		Unit
				Min	Max	Min	Max	Min	Max	
V_{IH}	HIGH-level	$ I_{O} < 1 \mu A$	5 V	3.5	-	3.5	-	3.5	-	V
	input voltage		10 V	7.0	-	7.0	-	7.0	-	V
			15 V	11.0	-	11.0	-	11.0	-	V
V _{IL}	LOW-level	$ I_{O} < 1 \mu A$	5 V	-	1.5	-	1.5	-	1.5	V
	input voltage		10 V	-	3.0	-	3.0	-	3.0	V
			15 V	-	4.0	-	4.0	-	4.0	V
V_{OH}	HIGH-level	$ I_{O} < 1 \mu A$	5 V	4.95	-	4.95	-	4.95	-	V
	output voltage		10 V	9.95	-	9.95	-	9.95	-	V
			15 V	14.95	-	14.95	-	14.95	-	V
V_{OL}	LOW-level	$ I_{O} < 1 \mu A$	5 V	-	0.05	-	0.05	-	0.05	V
	output voltage		10 V	-	0.05	-	0.05	-	0.05	V
			15 V	-	0.05	-	0.05	-	0.05	V
I _{OH}	HIGH-level	$V_0 = 2.5 \text{ V}$	5 V	-1.7	-	-1.4	-	-1.1	-	mΑ
	output current	$V_0 = 4.6 \text{ V}$	5 V	-0.52	-	-0.44	-	-0.36	-	mΑ
		$V_0 = 9.5 V$	10 V	-1.3	-	-1.1	-	-0.9	-	mΑ
		$V_0 = 13.5 \text{ V}$	15 V	-3.6	-	-3.0	-	-2.4	-	mΑ
I_{OL}	LOW-level	$V_0 = 0.4 \ V$	5 V	0.52	-	0.44	-	0.36	-	mΑ
	output current	$V_0 = 0.5 V$	10 V	1.3	-	1.1	-	0.9	-	mΑ
		$V_0 = 1.5 \text{ V}$	15 V	3.6	-	3.0	-	2.4	-	mΑ
I _I	input leakage current		15 V	-	±0.3	-	±0.3	-	±1.0	μΑ
I_{DD}	supply current	I _O = 0 A	5 V	-	20	-	20	-	150	μΑ
			10 V	-	40	-	40	-	300	μΑ
			15 V	-	80	-	80	-	600	μΑ
Cı	input capacitance		-	-	-	-	7.5	-	-	pF

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11. Dynamic characteristics

Table 7. Dynamic characteristics

 $T_{amb} = 25 \,^{\circ}C$; $V_{SS} = 0 \, V$; $C_L = 50 \, pF$; $t_r = t_f \le 20 \, ns$; unless otherwise specified.

	<u> </u>	<u> </u>			•				
Symbol	Parameter	Conditions	V_{DD}		Extrapolation formula[1]	Min	Тур	Max	Unit
t _{pd} propagation delay	propagation delay	$\text{RS} \to \text{Q3};$	5 V	[2]	183 ns + (0.55 ns/pF) C _L	-	210	420	ns
	see Figure 4	10 V		69 ns + (0.23 ns/pF) C _L	-	80	160	ns	
			15 V		42 ns + (0.16 ns/pF) C _L	-	50	100	ns
		$Qn \rightarrow Qn + 1;$	5 V		-	-	25	50	ns
		see Figure 4	10 V		-	-	10	20	ns
			15 V		-	-	6	12	ns
		$MR \rightarrow Qn;$	5 V		73 ns + (0.55 ns/pF) C _L	-	100	200	ns
		HIGH to LOW	10 V		29 ns + (0.23 ns/pF) C _L	-	40	80	ns
		see Figure 4	15 V		22 ns + (0.16 ns/pF) C _L	-	30	60	ns
t _t	transition time	ansition time see Figure 4	5 V	[3]	10 ns + (1.00 ns/pF) C _L	-	60	120	ns
			10 V		9 ns + (0.42 ns/pF) C_L	-	30	60	ns
			15 V		6 ns + (0.28 ns/pF) C_L	-	20	40	ns
t _W	pulse width	width minimum width; RS HIGH; see Figure 4 minimum width;	5 V			120	60	-	ns
			10 V			50	25	-	ns
			15 V			30	15	-	ns
			5 V			50	25	-	ns
		MR HIGH;	10 V			30	15	-	ns
		see Figure 4	15 V			20	10	-	ns
t _{rec}	recovery time	input MR;	5 V			160	80	-	ns
		see Figure 4	10 V			80	40	-	ns
			15 V			60	30	-	ns
f _{max}	maximum frequency	input RS;	5 V			4	8	-	ns
		see Figure 4	10 V			10	20	-	ns
			15 V			15	30	-	ns

^[1] The typical values of the propagation delay and transition times are calculated from the extrapolation formulas shown (C_L in pF).

^[2] t_{pd} is the same as t_{PHL} and t_{PLH}.

^[3] t_t is the same as t_{THL} and t_{TLH} .

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Table 8. Power dissipation

Dynamic power dissipation P_D and total power dissipation P_{tot} can be calculated from the formulas shown. $T_{amb} = 25 \,^{\circ}C$.

-				
Symbol	Parameter	Conditions	V_{DD}	Typical formula for P _D and P _{tot} (μW)[1]
P_{D}		5 V	$P_D = 700 \times f_i + \Sigma (f_0 \times C_L) \times V_{DD}^2$	
dissipation		10 V	$P_D = 3300 \times f_i + \Sigma (f_o \times C_L) \times V_{DD}^2$	
			15 V	$P_D = 8900 \times f_i + \Sigma (f_o \times C_L) \times V_{DD}^2$
P _{tot}	total power	when using	5 V	$P_{tot} = 700 \times f_{osc} + \Sigma (f_o \times C_L) \times V_{DD}^2 + 2 \times C_t \times V_{DD}^2 \times f_{osc} + 690 \times V_{DD}$
	dissipation	oscillator -	10 V	$P_{tot} = 3300 \times f_{osc} + \Sigma (f_o \times C_L) \times V_{DD}^2 + 2 \times C_t \times V_{DD}^2 \times f_{osc} + 6900 \times V_{DD}$
			15 V	$P_{tot} = 8900 \times f_{osc} + \Sigma (f_o \times C_L) \times V_{DD}^2 + 2 \times C_t \times V_{DD}^2 \times f_{osc} + 22000 \times V_{DD}$

[1] Where:

 f_i = input frequency in MHz; f_o = output frequency in MHz;

C_L = output load capacitance in pF;

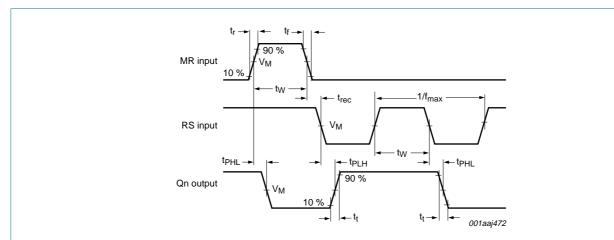
 V_{DD} = supply voltage in V;

 $\Sigma(f_0 \times C_L)$ = sum of the outputs;

C_t = timing capacitance (pF);

 f_{osc} = oscillator frequency (MHz).

12. Waveforms



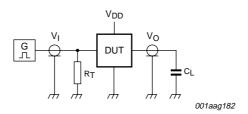
Measurement points are given in Table 9.

Fig 4. Waveforms showing propagation delays for MR to Qn and $\overline{\text{CP}}$ to Q0, minimum MR, and $\overline{\text{CP}}$ pulse widths

Table 9. Measurement points

Supply voltage	Input	Output
V_{DD}	V _M	V _M
5 V to 15 V	0.5V _{DD}	0.5V _{DD}

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Test data is given in Table 10.

Definitions for test circuit:

DUT = Device Under Test;

 C_L = load capacitance including jig and probe capacitance;

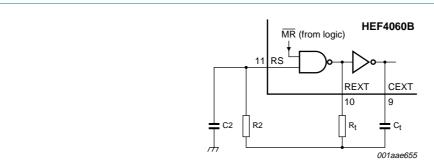
 R_T = termination resistance should be equal to the output impedance Z_0 of the pulse generator.

Fig 5. Test circuit for switching times

Table 10. Measurement point and test data

Supply voltage	Input	Load	
V_{DD}	VI	t _r , t _f	CL
5 V to 15 V	V _{SS} or V _{DD}	≤ 20 ns	50 pF

13. RC oscillator



Typical formula for oscillator frequency: $f_{osc} = \frac{1}{2.3 \times R_{\bullet} \times C_{\bullet}}$

Fig 6. External component connection for RC oscillator

13.1 Timing component limitations

The oscillator frequency is mainly determined by $R_t \times C_t$, provided $R_t << R2$ and $R2 \times C2 << R_t \times C_t$. The influence of the forward voltage across the input protection diodes on the frequency is minimized by R2. The stray capacitance C2 should be kept as small as possible. In consideration of accuracy, C_t must be larger than the inherent stray capacitance. R_t must be larger than the LOCMOS 'ON' resistance in series with it, which typically is $500~\Omega$ at $V_{DD} = 5~V$, $300~\Omega$ at $V_{DD} = 10~V$ and $200~\Omega$ at $V_{DD} = 15~V$.

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The recommended values for these components to maintain agreement with the typical oscillation formula are:

 $C_t \ge 100$ pF, up to any practical value, $10 \ k\Omega \le R_t \le 1 \ M\Omega.$

13.2 Typical crystal oscillator circuit

In <u>Figure 7</u>, R2 is the power limiting resistor. For starting and maintaining oscillation a minimum transconductance is necessary.

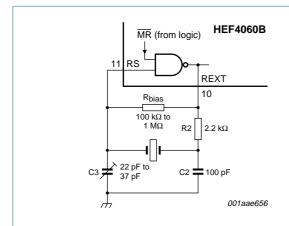
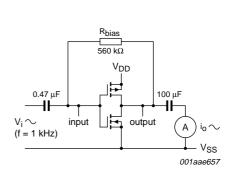


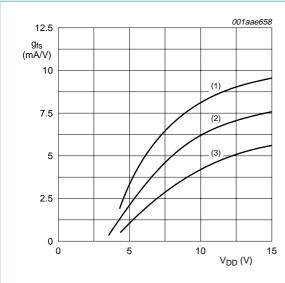
Fig 7. External component connection for crystal oscillator



 $g_{fs} = di_o/dv_i$ at v_o is constant (see also Figure 9); MR = LOW.

Fig 8. Test setup for measuring forward transconductance (g_{fs})

14-stage ripple-carry binary counter/divider and oscillator

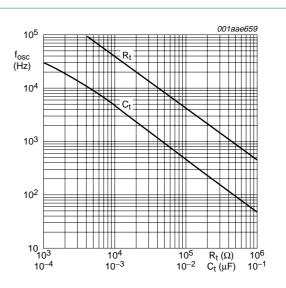


 $T_{amb} = 25 \, ^{\circ}C.$

- (1) Average + 2σ .
- (2) Average.
- (3) Average -2σ .

Where ' σ ' is the observed standard deviation.

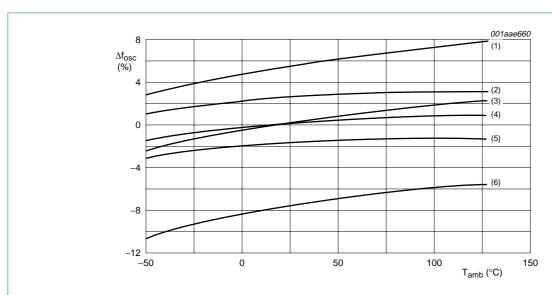
Fig 9. Typical forward transconductance g_{fs} as a function of the supply voltage



 $C_t \text{ curve at } R_t = 100 \text{ k}\Omega; \text{ R2} = 470 \text{ k}\Omega.$ $R_t \text{ curve at } C_t = 1 \text{ nF}; \text{ R2} = 5 \text{ R}_t.$

 V_{DD} = 5 V to 15 V; T_{amb} = 25 °C.

Fig 10. RC oscillator frequency as a function of R_t and C_t



Lines (1) and (2): $V_{DD} = 15 \text{ V}$.

Lines (3) and (4): V_{DD} = 10 V.

Lines (5) and (6): $V_{DD} = 5 \text{ V}$.

Lines (1), (3), (6): R_t = 100 k Ω ; C_t = 1 nF; R2 = 0 W.

Lines (2), (4), (5): $R_t = 100 \text{ k}\Omega$; $C_t = 1 \text{ nF}$; $R2 = 300 \text{ k}\Omega$.

Referenced at: f_{osc} at T_{amb} = 25 °C and V_{DD} = 10 V.

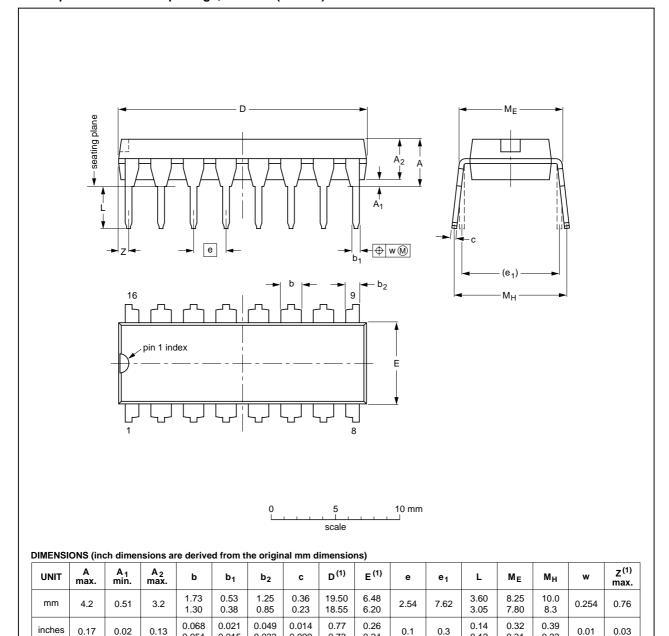
Fig 11. Oscillator frequency deviation (Δf_{osc}) as a function of ambient temperature

14-stage ripple-carry binary counter/divider and oscillator

14. Package outline

DIP16: plastic dual in-line package; 16 leads (300 mil)

SOT38-4



1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

0.015

0.033

0.009

0.051

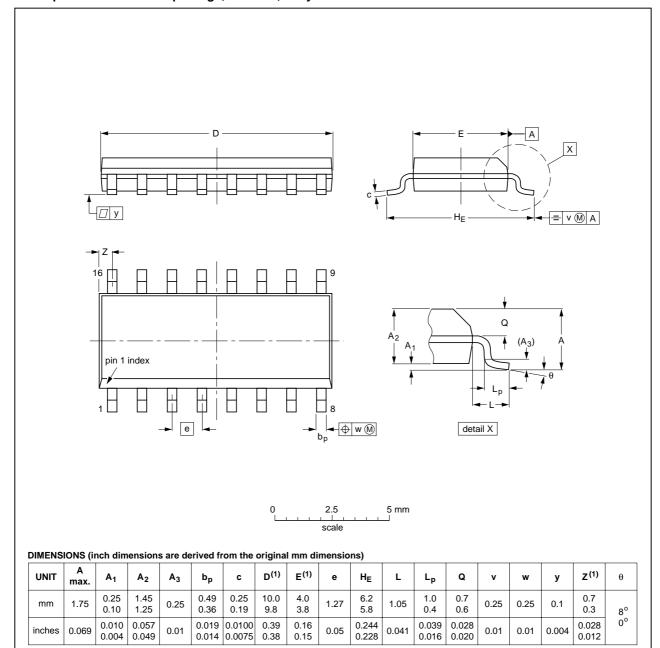
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VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT38-4						95-01-14 03-02-13

Fig 12. Package outline SOT38-4 (DIP16)

14-stage ripple-carry binary counter/divider and oscillator

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE	REFERENCES				EUROPEAN	ICCUE DATE	
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT109-1	076E07	MS-012				99-12-27 03-02-19	

Fig 13. Package outline SOT109-1 (SO16)

14-stage ripple-carry binary counter/divider and oscillator

15. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
HEF4060B_5	20091127	Product data sheet	-	HEF4060B_4
Modifications:	 Section 9 "R 	ecommended operating condi	<u>tions"</u> Δt/ΔV values υ	ıpdated.
HEF4060B_4	20090817	Product data sheet	-	HEF4060B_CNV_3
HEF4060B_CNV_3	19950101	Product specification	-	HEF4060B_CNV_2
HEF4060B_CNV_2	19950101	Product specification	-	-

14-stage ripple-carry binary counter/divider and oscillator

16. Legal information

16.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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